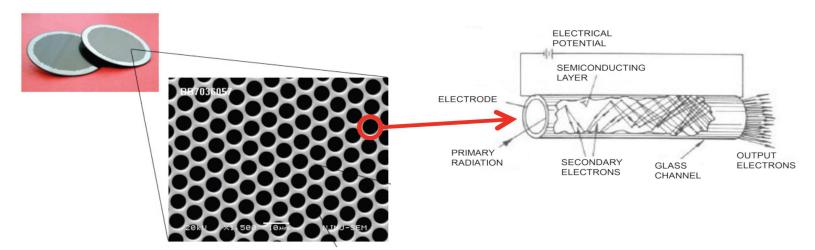
Optimization of 33 mm Operational Parameters

Bernhard Adams, <u>Andrey Elagin</u>, Razib Obaid, Alexander Vostrikov, Matt Wetstein

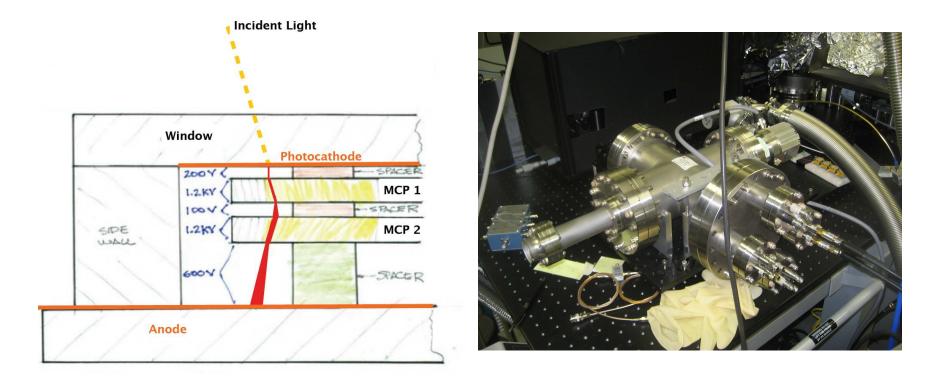
Goals



Understand MCP physics characteristic

- MgO vs Al₂O₃ (Matt's talk)
- Gain vs voltage (this talk)
- How resistance affects MCP performance?
- Feedback to the MCP simulation (Matt's talk)
- What are the key elements for best timing performance? What we learn with 33 mm can be useful for 8" setup

Experimental Setup



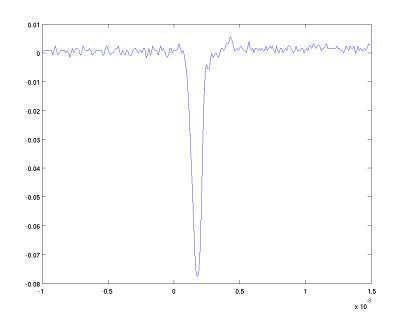
5 voltage gaps: PC, MCP1, inter MCP, MCP2, Anode Typical voltages: ~200V, ~1kV, ~100V, ~1kV, ~1.2kV

Data

Single photo-electron operation

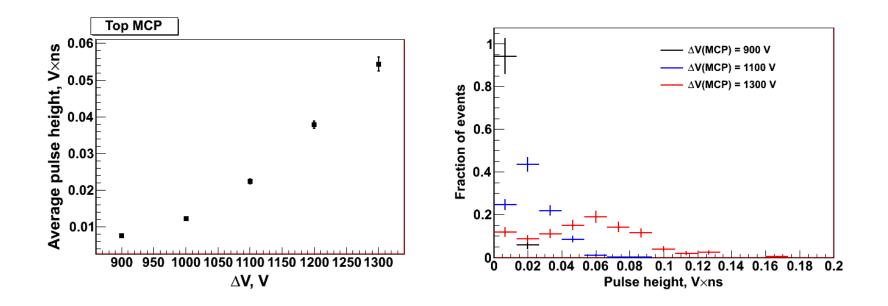
Anode pulses:

- Gain
- Shape
- Timing



Voltages scan: Top MCP

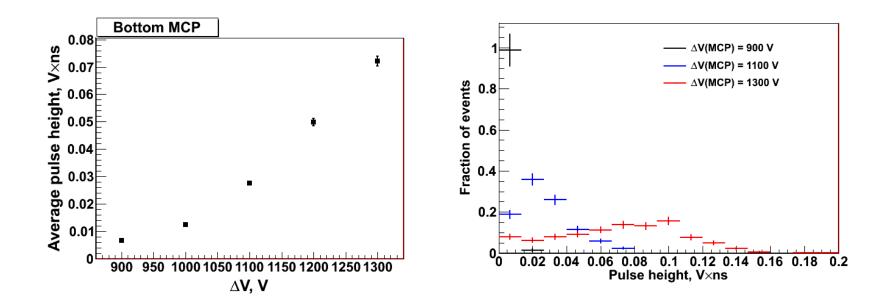
MgO MCP pair with ~1 GOhm matched resistance



Pulse height = Integral of the pulse

Voltages scan: Bottom MCP

MgO MCP pair with ~1 GOhm matched resistance

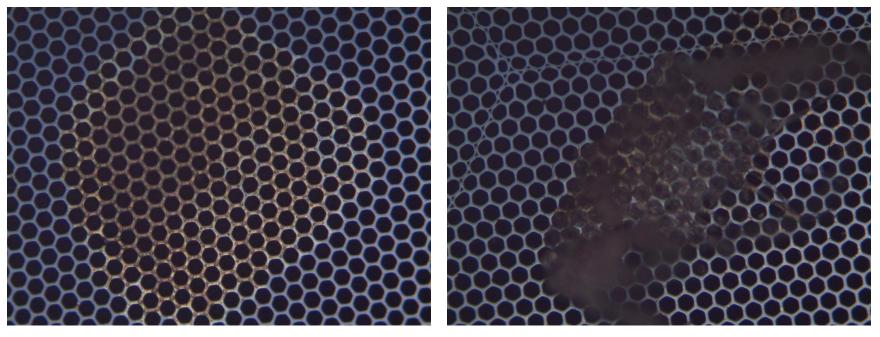


There is a HV limit

~2kV across MCP

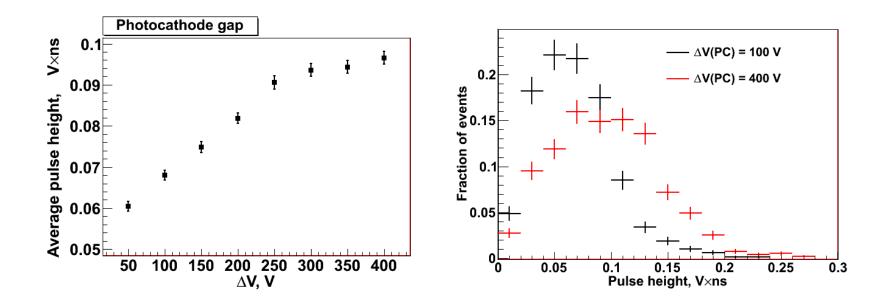
Front side

Bottom side



Voltages scan: Photocathode Gap

MgO MCP pair with ~40 MOhm matched resistance



Summary and plans

- We are learning about MCP from 33 mm setup at the laser lab at Argonne APS
- Began systematic studies of voltage gaps
- Very close to substitute the scope data by the data from the chip (Eric's talk)
- Focus on timing characteristics